

# Citations for Target : **InP**

<b>Pub. Year</b>	<b>Authors, Title, Journal Citation and Comments</b>	<b>Citation Numb</b>
<b>1979</b>	Donnelly, J. P. Armiento, C. A. 'Beryllium-Ion Implantation in InP and In(1-X)Ga(X)As(Y)P(1-Y)' <i>Appl. Phys. Letters, 34, 96-99 (1979)</i> <i>Comment : R. 50-400 keV Be -&gt; InP, InGaAsP</i>	<b>1979-Donn</b> 1208
<b>1979</b>	Lorenzo, J. P. Davies, D. E. Ryan, T. G. 'Anodic Oxidation and Electrical Carrier Concentration Profiles of Ion-Implanted InP' <i>J. Electrochem. Soc., 126, 118-121 (1979)</i> <i>Comment : R, dR. 1 MeV S, Si -&gt; InP</i>	<b>1979-Lore</b> 1222
<b>1984</b>	Khodyrev, V. A. Mizgulin, V. N. Sirotinin, E. I. Tulinov, A. F. 'Stopping Cross Sections of 80-500 keV Protons in Phosphorus Compounds' <i>Rad. Effects, 83, 21-37 (1984)</i> <i>Comment : S. H (80-500 keV) -&gt; InP, GaP, ZnSiP2</i>	<b>1984-Khod</b> 1690
<b>1987</b>	Lee, S. R. Hart, R. R. 'Stopping Power Measurements of 20-180 keV 1H and 4He in Indium Phosphide using Thick Target Backscattering' <i>Nucl. Inst. Methods, B28, 470-480 (1987)</i> <i>Comment : S. H, He (20-180 keV) -&gt; InP</i>	<b>1987-Lee</b> 1392
<b>1994</b>	Hetherington, D. W. 'Measuring the Stopping Power for Alpha Particles Channeled in InP' <i>Nucl. Inst. Methods, B90, 84-87 (1994)</i> <i>Comment : S. He (2.5 MeV) -&gt; InP (channeled)</i>	<b>1994-Heth</b> 1856
<b>1996</b>	Hetherington, D. W. 'Measurements of the Random and Channeled Stopping Powers for He Ions in InP' <i>Nucl. Inst. Methods, B115, 319-322 (1996)</i> <i>Comment : S. He (0.6-3.5 MeV) -&gt; InP (Random and channeled)</i>	<b>1996-Heth</b> 1759